NSN 5962-01-429-3508

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View Online at https://aerobasegroup.com/nsn/5962-01-429-3508

Body Length:
0.640 inches
Body Width:
0.420 inches
Body Height:
0.090 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Pacer special
Features Provided:
Bipolar and electrostatic sensitive and monolithic and programmed and radiation hardened
Inclosure Material:
Metal and ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Criticality Code Justification:
Cbbl
Case Outline Source And Designator:
F-6 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, read only memory
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Rom
Special Features:
Altered item, altered by programming; program media id 5055507, file name horizb.4; make from p/n 5962-8552704kx
Nuclear Hardness Critical Feature:
Hardened

Test Data Document:

96906-mil-std883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type And Quantity:

24 flat leads

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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